



TIGER ELECTRONIC CO.,LTD

US1A THRU US1M

1.0 AMP. HIGH EFFICIENT RECOVERY SURFACE MOUNT RECTIFIERS

Voltage Range
50 to 1000 VOLTS
Current
1.0 Amperes

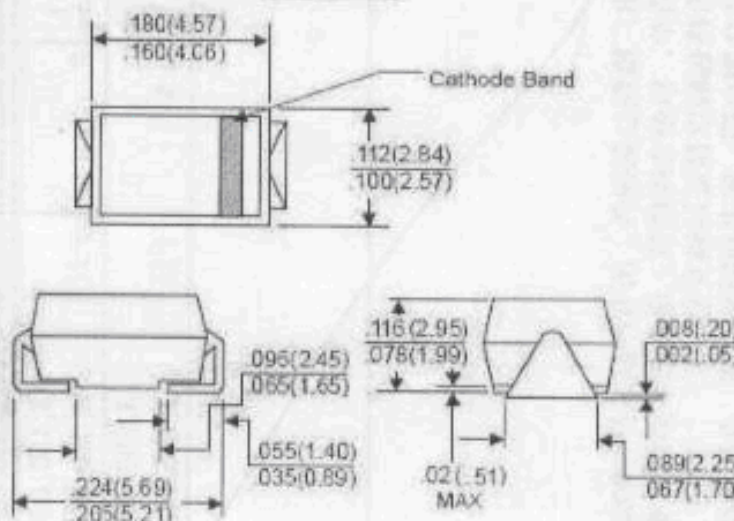
Features

- Glass passivated junction chip
- For surface mounted application
- Low profile package
- Built-in strain relief
- Ideal for automated placement
- Easy pick and place
- Ultrafast recovery time for high efficiency
- Low forward voltage, low power loss
- High temperature soldering guaranteed:
260°C/10 seconds on terminals
- Plastic material used carries Underwriters
Laboratory Classification 94V0

Mechanical Data

- Cases: Molded plastic
- Terminals: Solder plated, solderable per
MIL-STD-750, Method 2026
- Polarity: Indicated by cathode band
- Weight: 0.064 gram

SMA-W



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	US1A	US1B	US1D	US1G	US1J	US1K	US1M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ $T_L=110^{\circ}\text{C}$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single -half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.0				1.7			V
Maximum DC Reverse Current @ $T_A=25^{\circ}\text{C}$ at Rated DC Blocking Voltage @ $T_A=125^{\circ}\text{C}$	I_R	5.0 150							μA μA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	50				75			nS
Typical Junction Capacitance (Note 2)	C_j	15				10			pF
Maximum Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$	75 27							$^{\circ}\text{C/W}$
Operating Temperature Range	T_J	-55 to +150							$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 to + 150							$^{\circ}\text{C}$

- Notes:
1. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
 2. Measured at 1 MHz and Applied $V_R=4.0$ Volts
 3. P.C.B. Mounted on $0.2 \times 0.2"$ ($5.0 \times 5.0\text{mm}$) Copper Pad Area.